NSN 5961-01-339-3269

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Inclosure Material:
Metal
Overall Length:
6.6 millimeters
Terminal Length:
12.7 millimeters
Overall Diameter:
9.4 millimeters
End Application:
Tactical air operations central an/tyq-2 (v) 1
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-39
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Terminal
Terminal Circle Diameter:
5.08 millimeters
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
40.0 collector to base voltage/static/emitter open and 40.0 collector to emitter voltage/static/base open
Current Rating Per Characteristic:
600.00 milliamperes source cutoff current
Power Rating Per Characteristic:
600.0 milliwatts small-signal input power, common-collector preset
Transfer Ratio:
125.0 static forward current transfer ratio, common-emitter
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnp
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:

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Demilitarization:

No

Fiig:

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